- Ultra-Fast Operation . . . 7.8 ns (Typ)
- **Low Positive Supply Current** 10.6 mA (Typ)
- Operates From a Single 5-V Supply or From a Split ±5-V Supply
- **Complementary Outputs**
- **Low Offset Voltage**
- No Minimum Slew Rate Requirement
- **Output Latch Capability**
- **Functional Replacement to the LT1016**

### description

The TL3016 is an ultra-fast comparator designed to interface directly to TTL logic while operating from either a single 5-V power supply or dual ±5-V supplies. It features extremely tight offset voltage and high gain for precision applications. It has complementary outputs that can be latched using the LATCH ENABLE terminal. Figure 1 shows the positive supply current of this comparator. The TL3016 only requires 10.6 mA (typical) to achieve a propagation delay of 7.8 ns.

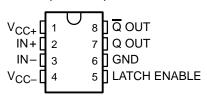
The TL3016 is a pin-for-pin functional replacement for the LT1016 comparator, offering higher speed operation but consuming half the power.

#### **AVAILABLE OPTIONS**

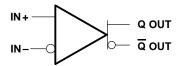
	PACKAG	CHIP		
TA	SMALL OUTLINE <sup>†</sup> (D)	TSSOP (PW)	FORM <sup>‡</sup> (Y)	
0°C to 70°C	TL3016CD	TL3016CPWLE	TL3016Y	
-40°C to 85°C	TL3016ID	TL3016IPWLE	_	

<sup>†</sup> The PW packages are available left-ended taped and reeled only.

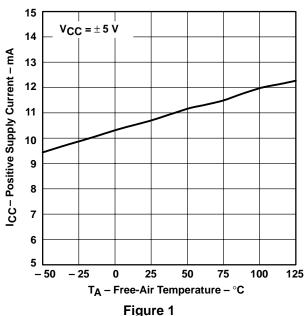
#### D AND PW PACKAGE (TOP VIEW)



## symbol (each comparator)



# **POSITIVE SUPPLY CURRENT** FREE-AIR TEMPERATURE







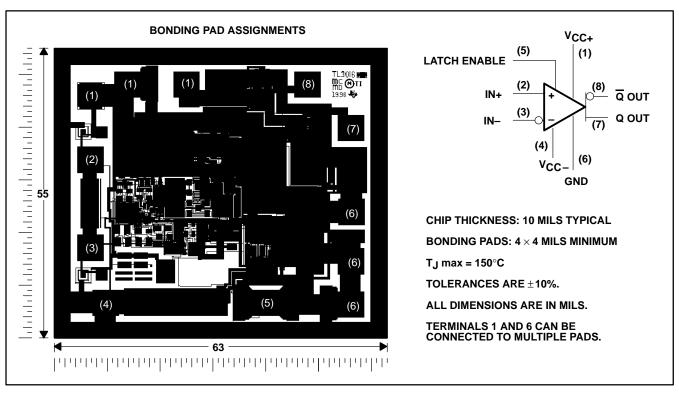
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



<sup>‡</sup> Chip forms are tested at  $T_A = 25^{\circ}C$  only.

## TL3016Y chip information

This chip, when properly assembled, displays characteristics similar to the TL3016C. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. Chips may be mounted with conductive epoxy or a gold-silicon preform.



COMPONENT COUNT					
Bipolars	53				
MOSFETs	49				
Resistors	46				
Capacitors	14				



# TL3016, TL3016Y ULTRA-FAST LOW-POWER PRECISION COMPARATORS

SLCS130B - MARCH 1997 - REVISED APRIL 1997

# absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V <sub>DD</sub> (see Note 1)	
Differential input voltage, V <sub>ID</sub> (see Note 2)	
Input voltage range, V <sub>1</sub>	
Input voltage, V <sub>I</sub> (LATCH ENABLE)	
Output current, IO	± 20 mA
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T <sub>A</sub>	40°C to 85°C
Storage temperature range, T <sub>sta</sub>	– 65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

NOTES: 1. All voltage values, except differential voltages, are with respect to network ground.

2. Differential voltages are at IN+ with respect to IN-.

#### **DISSIPATION RATING TABLE**

PACKAGE	$T_{\mbox{\scriptsize A}} \leq 25^{\circ}\mbox{\scriptsize C}$ POWER RATING	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING
D	725 mW	5.8 mW/°C	464 mW
PW	525 mW	4.2 mW/°C	336 mW



<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

# TL3016, TL3016Y ULTRA-FAST LOW-POWER PRECISION COMPARATORS

SLCS130B - MARCH 1997 - REVISED APRIL 1997

# electrical characteristics at specified operating free-air temperature, $\rm V_{DD}$ = $\pm 5$ V, $\rm V_{LE}$ = 0 (unless otherwise noted)

PARAMETER		TEST CONDITIONS <sup>†</sup>		TL3016C		TL3016I			UNIT
	PARAMETER	TEST CONDITIONS <sup>†</sup>	MIN	TYP‡	MAX	MIN	TYP‡	MAX	UNII
VIO	Input offset voltage	$T_A = 25^{\circ}C$		0.5	3		0.5	3	mV
۷IO	input onset voitage	T <sub>A</sub> = full range			3.5			3.5	IIIV
αVIO	Temperature coefficient of input offset voltage			-4.8			-4.5		μV/°C
li o	Input offset current	T <sub>A</sub> = 25°C		0.1	0.6		0.1	0.6	μА
ΙO	input onset current	T <sub>A</sub> = full range			0.9			1.3	μΑ
l.a	Input bias current	T <sub>A</sub> = 25°C		0.6	7.5		0.6	7.5	μА
ΙΒ	input bias current	T <sub>A</sub> = full range			8			10	μΑ
V. 0.5	Common-mode input	$V_{DD} = \pm 5 \text{ V}$	-3.7	5	3.5	-3.75		3.5	V
VICR	voltage range	V <sub>DD</sub> = 5 V	1.2	5	3.5	1.25		3.5	l v l
CMRR	Common-mode rejection ratio	$-3.75 \le V_{IC} \le 3.5 \text{ V}, \qquad T_A = 25^{\circ}\text{C}$	8	97		80	97		dB
16-2-1-	Supply-voltage rejection	Positive supply: 4.6 V $\leq$ +V <sub>DD</sub> $\leq$ 5.4 V T <sub>A</sub> = 25°C	, 6	72		60	72		dB
kSVR	ratio	Negative supply: $-7 \text{ V} \le -V_{DD} \le -2 \text{ V}$ T <sub>A</sub> = 25°C	', 8i	0 100		80	100		as
\/o:	Low-level output voltage	$ \begin{aligned} &I_{\text{(sink)}} = 4 \text{ mA}, & \text{V+} \leq 4.6 \text{ V}, \\ &T_{\text{A}} = 25^{\circ}\text{C} \end{aligned} $		500	600		500	600	mV
VOL	Low-level output voltage	$\begin{aligned} &I_{\text{(sink)}} = 10 \text{ mA}, & \text{V+} \leq 4.6 \text{ V}, \\ &T_{\text{A}} = 25^{\circ}\text{C} \end{aligned}$		750			750		IIIV
Vон	High-level output voltage	$V+ \le 4.6 \text{ V},$ $I_O = 1 \text{ mA},$ $T_A = 25^{\circ}\text{C}$	3.	6 3.9		3.6	3.9		V
VOH	r ligh-level output voltage	$V+ \leq 4.6 \text{ V}, \\ T_A = 25^{\circ}\text{C}$ $I_O = 10 \text{ mA},$	3.	4 3.7		3.4	3.7		V
inn	Positive supply current	Τ <sub>Δ</sub> = full range		10.6	12.5		10.6	12.5	mA
IDD	Negative supply current	TA = Iuii Tange	-1.	3 –1.3		-2.4	-1.3		IIIA
V <sub>IL</sub>	Low-level input voltage (LATCH ENABLE)				0.8			0.8	V
VIH	High-level input voltage (LATCH ENABLE)			2		2			V
1	Low-level input current	V <sub>LE</sub> = 0		0	1		0	1	
IIL	(LATCH ENABLE)	V <sub>LE</sub> = 2 V		24	39		24	45	μΑ

<sup>†</sup> Full range for the TL3016C is  $T_A = 0^{\circ}$ C to  $70^{\circ}$ C. Full range for the TL3016I is  $T_A = -40^{\circ}$ C to  $85^{\circ}$ C. ‡ All typical values are measures with  $T_A = 25^{\circ}$ C.



# switching characteristics, $V_{DD} = \pm 5 \text{ V}$ , $V_{LE} = 0$ (unless otherwise noted)

PARAMETER		TEST SOMBITIONS		TL3016C		TL3016I			UNIT		
	FARAMETER	TEST CONDITIONS†		MIN	TYP	MAX	MIN	TYP	MAX	ONII	
$\Delta V_{I} = 100$		$\Delta V_{\parallel} = 100 \text{ mV},$	T <sub>A</sub> = 25°C		7.8	8.8		7.8	8.8		
tod1 Propagation delay time±	$V_{OD} = 5 \text{ mV}$	T <sub>A</sub> = full range		7.8	10.4		7.8	11.4	ns		
	$\Delta V_{I} = 100 \text{ mV},$	T <sub>A</sub> = 25°C		7.6	8.6		7.6	8.6			
	Vol		T <sub>A</sub> = full range		7.6	10.2		7.6	11.2		
<sup>t</sup> sk(p)	Pulse skew ( t <sub>pd+</sub> - t <sub>pd-</sub>  )	$\Delta V_I = 100 \text{ mV},$ $T_A = 25^{\circ}\text{C}$	$V_{OD} = 5 \text{ mV},$		0.5			0.5		ns	
t <sub>su</sub>	Setup time, LATCH ENABLE				2.5	·		2.5		ns	

#### **TYPICAL CHARACTERISTICS**

#### **Table of Graphs**

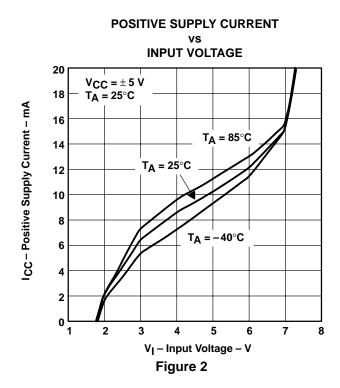
			FIGURE
		vs Input voltage	2
ICC	Positive supply current	vs Frequency	3
		vs Free-air temperature	4
ICC	Negative supply current	vs Free-air temperature	5
		vs Overdrive voltage	6
		vs Supply voltage	7
<sup>t</sup> pd	Propagation delay time	vs Input impedance	8
		vs Load capacitance	9
		vs Free-air temperature	10
VIC	Common-mode input voltage	vs Free-air temperature	11
	Threshold voltage (LATCH ENABLE)	vs Free-air temperature	12
\/ -	Output voltage	vs Output source current	13
VO	Output voltage	vs Output sink current	14
l <sub>l</sub>	Input current (LATCH ENABLE)	vs Input voltage	15

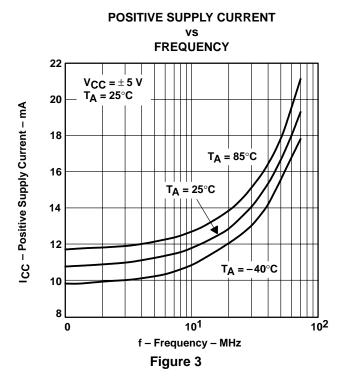


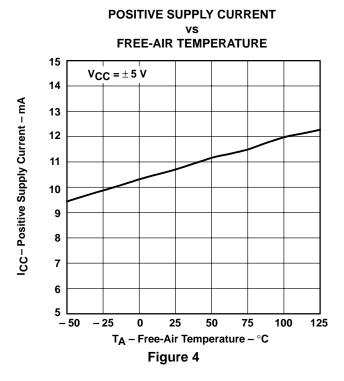
Full range for the TL3016C is 0°C to 70°C. Full range for the TL3016I is -40°C to 85°C.

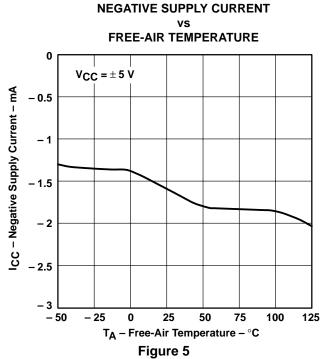
† tpd1 cannot be measured in automatic handling equipment with low values of overdrive. The TL3016 is 100% tested with a 1-V step and 500-mV overdrive at TA = 25°C only. Correlation tests have shown that tpd1 limits given can be ensured with this test, if additional dc tests are performed to ensure that all internal bias conditions are correct. For low overdrive conditions, Vos is added to the overdrive.

#### TYPICAL CHARACTERISTICS

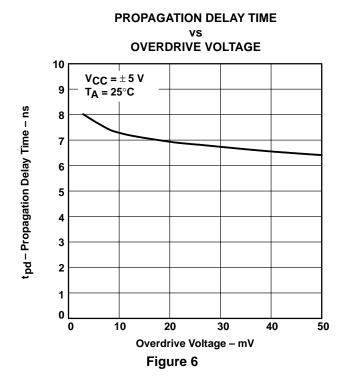


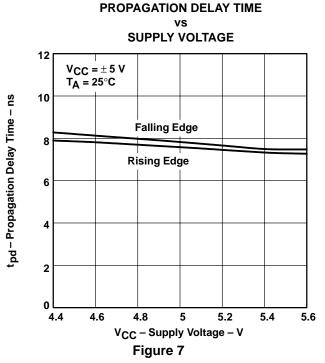




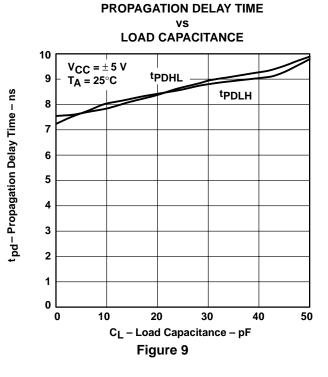


#### TYPICAL CHARACTERISTICS



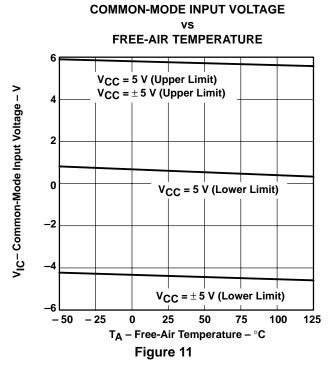


#### PROPAGATION DELAY TIME **INPUT IMPEDANCE** 20 $V_{CC} = \pm 5 V$ 18 $T_A = 25^{\circ}C$ t pd- Propagation Delay Time - ns 16 14 5 mV 12 10 8 20 mV 6 4 2 ٥<u></u> 50 150 200 250 300 $Z_O$ – Input Impedance – $\Omega$ Figure 8

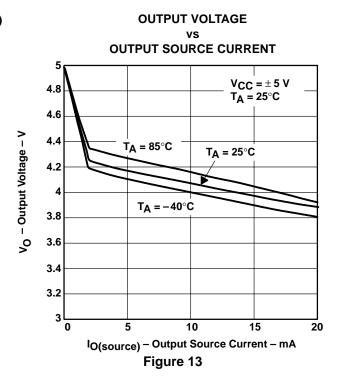


#### TYPICAL CHARACTERISTICS

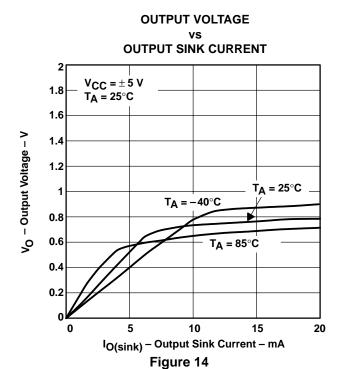
# **PROPAGATION DELAY TIME** FREE-AIR TEMPERATURE 25 $V_{CC}$ = $\pm$ 5 Vt pd - Propagation Delay Time - ns 20 15 Rising Edge 10 **Falling Edge** 5 - 50 - 25 25 50 75 100 125 $T_A$ – Free-Air Temperature – $^{\circ}$ C Figure 10

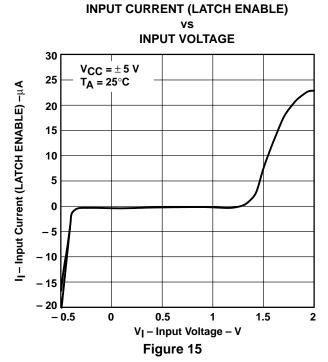


# **INPUT THRESHOLD VOLTAGE (LATCH ENABLE)** FREE-AIR TEMPERATURE V<sub>IT</sub> – Input Threshold Voltage (LATCH ENABLE) – V $V_{CC} = \pm 5 V$ 1.8 1.6 1.4 1.2 0.8 0.6 0.4 0.2 -50 -25 T<sub>A</sub> - Free-Air Temperature - °C Figure 12



## **TYPICAL CHARACTERISTICS**



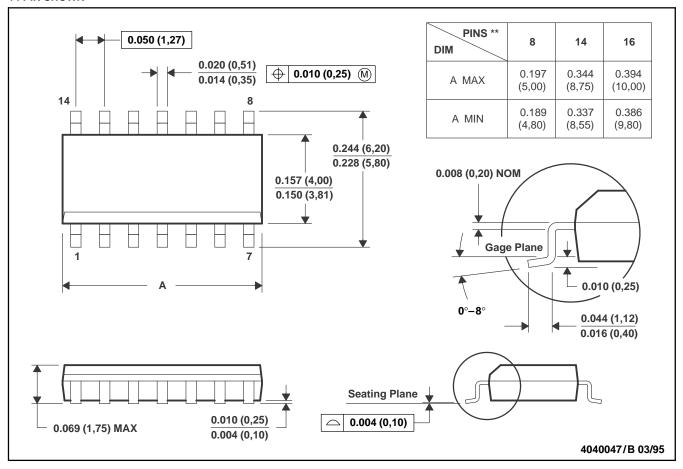


# **MECHANICAL INFORMATION**

# D (R-PDSO-G\*\*)

#### PLASTIC SMALL-OUTLINE PACKAGE

#### 14 PIN SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).
- D. Four center pins are connected to die mount pad.
- E. Falls within JEDEC MS-012

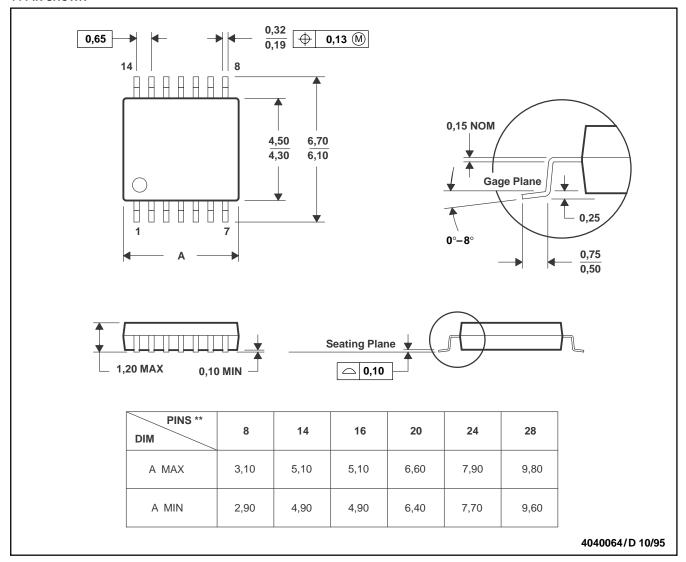


# **MECHANICAL INFORMATION**

# PW (R-PDSO-G\*\*)

## PLASTIC SMALL-OUTLINE PACKAGE

#### 14 PIN SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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